Integrating multiple stubs in stepped-impedance filter aiming for high selectivity

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Abstract: A design technique to include multiple and fully-controlled transmission zeros (TZs) in the frequency response of rectangular waveguide commensurate-line stepped-impedance filters is presented in this letter. These bandpass filters (BPFs) are known for having reduced sensitivities against manufacturing inaccuracies and are composed of multiple waveguide sections. In order to improve their selectivity, λg/4 and λg/2-stubs are included to create multiple TZs around the passband. The proposed technique allows us to add multiple stubs in a single section and, therefore, only minor adjustments in the affected part of the filter are required, which simplifies the overall design process. The technique has been verified with a design example with four TZs (two on each side) near the passband.

Introduction: High selectivity is a key factor to suppress the interferences that exist at the nearby frequencies to the passband of a filter. Different techniques are used to generate transmission zeros (TZs) near the passband to enhance this parameter, for instance the cross-couplings that exist at the nearby frequencies to the passband of a filter. High selectivity is a key factor to suppress the interferers.

Design method: As it is detailed in [5, 6], in order to design a stepped-impedance filter employing these methods to lead to filters with complex geometries or devices that require long optimization processes to be designed.

Rectangular waveguide stepped-impedance filters based on commensurate lines are typically employed to obtain low-pass waveguide filters [4]. In [5, 6], the first passband replica of these structures was used to design bandpass filters (BPFs), significantly increasing the fabrication tolerances compared with the classical inductive iris filters. These BPFs are implemented with stepped-impedance waveguide sections and allow novel topologies, such as the meandered filters proposed in [7] to reduce the overall footprint. Recently, a modular design strategy to generate TZs in the stepped-impedance BPFs has been presented in order to improve their selectivity [8], where two λg/4-stubs were added to two different waveguide sections to create two TZs. In this paper, we will significantly extend this idea, proposing a technique where several stubs of different lengths will be included in the same waveguide section. Only that section would need to be re-designed for the inclusion of an arbitrary number of TZs at fully controlled positions below and above the passband while the rest of the filter can remain unaltered.

Firstly, an independent DE must be defined and simulated, obtaining their overall footprint. Recently, a modular design strategy to generate TZs in the stepped-impedance BPFs has been presented in order to improve their selectivity [8], where two λg/4-stubs were added to two different waveguide sections to create two TZs. In this paper, we will significantly extend this idea, proposing a technique where several stubs of different lengths will be included in the same waveguide section. Only that section would need to be re-designed for the inclusion of an arbitrary number of TZs at fully controlled positions below and above the passband while the rest of the filter can remain unaltered.

Fig. 1 Schematic of (a) DE and (b) M-SADE (M = 4 in this case).

Fig. 2 Frequency response of a DE (black line), SADE with λg/4-stub (blue line), and SADE with 3λg/4-stub (red line). Dotted line: |S11|, solid line: |S21|.

where c is the speed of light in vacuum and $f_0$ is the central frequency of the passband calculated as in [7]. As the BPF is based on commensurate lines, the electrical length $\pi - \theta_1$ and $\pi + \theta_1$ of the commensurate lines correspond to $f_1$ and $f_2$, respectively, where $\pi$ is the electrical length that corresponds to the middle frequency of the passband and $\theta_1$ is given by (2) [7]

\[
\theta_1 = \pi \times \frac{\lambda_{f_1} - \lambda_{f_2}}{\lambda_{f_1} + \lambda_{f_2}}
\]

being $\lambda_{g}$ the wavelength related to frequency $f_0$. Therefore, all the waveguide sections should have the same length, $l_n$, ideally equal to $\lambda_{g}/2$. However, due to the discontinuities at the junctions between the different sections, these lengths must be modified to compensate for the fringing field effect. This can be done by satisfying the phase conditions for $S_{11}$ and $S_{21}$ given also in [7].

Once the stepped-impedance baseline filter is designed, design entities (DEs) consisting of a complete waveguide section and adjacent sections of half-length as shown in Figure 1a can be defined. This strategy was employed in [8] to modify the DE and include a $\lambda_{g}/4$-stub in the sections, obtaining a stub-added design entity (SADE) to create a TZ in the frequency response. However, the design technique in [8] permitted only one TZ per section and a different section had to be used per TZ. In this work, a multiple SADE (M-SADE) is proposed to include multiple TZs in a single section (Figure 1b), therefore simplifying the design process as the rest of the filter can be kept unaltered.

Firstly, an independent DE must be defined and simulated, obtaining a frequency response as the one shown in Figure 2 (black line). Then, any stub of length equal to odd multiples of $\lambda_{g}/4$ can be used to create TZs in the filter response. In Figure 2, the frequency response of a SADE with a $\lambda_{g}/4$-stub is also shown (blue line). As can be seen, the inclusion of a $\lambda_{g}/4$-stub to introduce a TZ close to the pole has shifted the pole towards lower frequencies, which will require a slight adjustment of the section length to replicate the rest of the original frequency response of the DE. It is interesting to note that when a $3\lambda_{g}/4$-stub is included in the
DE, the shift of the corresponding pole is almost negligible (the red line in Figure 2), which would facilitate in some cases the design process. As explained in [3], the TZ associated with this longer stub has a narrower bandwidth compared with the TZ due to a λg/4-stub, which permits us to place the TZ close to the passband while barely affecting the rest of the original response. Then, the use of λg/4-stubs may be a good choice when TZs very near the passband are needed.

In general, a combination of multiple (M) λg/4- or 3λg/4-stubs can be used in the DE to design the new M-SADE depending on the frequency needs. Although it is not mandatory, the stubs should be placed at the ends of the sections since this facilitates the inclusion of multiple TZs in the frequency response without generating unwanted resonances. In Figure 3a, two stubs of lengths λg/4 and 3λg/4 are employed to create TZs at the lower and upper sides of the intrinsic pole of the DE. In order to maintain the rest of the frequency response of the baseline filter, the original frequency response of the DE must be replicated (except for the TZs, of course) by the M-SADE by adjusting b1 and l1 to fulfill (3). [8]

$$S_{11\text{-DE}}(f) = S_{11\text{-M-SADE}}(f) \quad f_1 < f < f_2$$

(3)

The frequency response of the M-SADE (M = 2) is shown in Figure 4 (red line). Similarly, an M-SADE with M = 3 (Figure 3b) can be employed to include 3 TZs (2 TZs above and 1 TZ below in this case), as shown in Figure 4 (blue line). In this way, an M-SADE with multiple stubs can be designed to implement the desired combination of TZs and, afterwards, simply added to the baseline filter replacing the corresponding DE.

**Design example:** According to the design method explained in the last section, the first step is to design a stepped-impedance BPF based on commensurate lines. For instance, for Ku-band applications [5, 6], seventh-order (N = 7) Chebyshev bandpass response can be achieved between f1 = 10.70 GHz and f2 = 12.75 GHz with in-band return losses better than 20 dB using the following normalized impedances Z1 = Z = 1.84, Z0 = Z0 = 0.40, Z1 = Z2 = 3.32, Z = 0.32, assuming a constant width equal to a = 19.05 mm and an initial height bt = 3.8 mm. Afterwards, the heights of the sections, t, for the corresponding Zs are calculated using (1) and l is adjusted satisfying the phase conditions given in [7]. The dimensions of the filter are listed in Table 1 and the frequency response in Figure 8 (blue line).

Once the baseline filter has been designed for the required specifications, the next step is to design an M-SADE to create multiple TZs at the desired frequencies. A 4-SADE is designed to replace the first DE in the filter, DE1, having four stubs which are employed to create TZs at 9.5, 10, 13.5, and 13.9 GHz. Specifically, λg/4-stubs are used to create TZs below the passband (9.5, 10 GHz) and 3λg/4-stubs are employed for the TZs above it (13.5 and 13.9 GHz). However, other combinations may be also used. In order to fulfill (3), the parameters b1 and l1 are slightly adjusted to replicate the frequency response of DE1. The width of the stubs, w, is fixed to 1.05 mm to facilitate a standard computer numerical control (CNC) milling manufacturing process. The frequency response of the DE compared with the M-SADE is shown in Figure 5.

In order to reduce the total footprint of the device the stubs can be folded if needed, having no effect on the 4-SADE frequency response (see Figure 5). Finally, the 4-SADE is integrated in the baseline filter replacing DE1. The resulting structure obtained is shown in Figure 6.

**Table 1. Dimensions of the filter structures (all parameters in mm)**

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Baseline filter</th>
<th>Final device*</th>
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<tbody>
<tr>
<td>b1</td>
<td>-</td>
<td>8.48; 8.71</td>
</tr>
<tr>
<td>b2</td>
<td>-</td>
<td>6.42; 8.50</td>
</tr>
<tr>
<td>b3</td>
<td>-</td>
<td>4.86; 5.58</td>
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<tr>
<td>b4</td>
<td>3.80; 8.68</td>
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<tr>
<td>b5</td>
<td>6.99; 17.80</td>
<td>4.92; 23.20</td>
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<tr>
<td>b6</td>
<td>1.50; 15.84</td>
<td>1.80; 15.23</td>
</tr>
<tr>
<td>b7</td>
<td>12.62; 17.49</td>
<td>14.70; 17.44</td>
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<tr>
<td>b9</td>
<td>1.50; 15.84</td>
<td>1.64; 15.79</td>
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<tr>
<td>b10</td>
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<td>7.10; 17.85</td>
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<tr>
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<td>-</td>
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<tr>
<td>b14</td>
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<tr>
<td>lsub1</td>
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<tr>
<td>lsub2</td>
<td>-</td>
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</tr>
<tr>
<td>lsub3</td>
<td>-</td>
<td>6.05; 7.75; 2.85</td>
</tr>
</tbody>
</table>

![Fig. 3](image-url) Schematic of (a) M-SADE with M = 2 (one λg/4-stub and one 3λg/4-stub), (b) M-SADE with M = 3 (one λg/4-stub and two 3λg/4-stubs).

![Fig. 4](image-url) Frequency response of a DE (black line), M-SADE with M = 2 (red line), and M-SADE with M = 3 (blue line). Dotted line: |S11|, solid line: |S11|.

![Fig. 5](image-url) Frequency response of the DE (black line), 4-SADE with straight stubs (blue line) and 4-SADE with folded stubs used in the design example (red line). Dotted line: |S11|, solid line: |S11|. Inset: schematic of the DE1 and the 4-SADE with straight stubs.
After that, the parameters are optimized to obtain the required response to consider the effect of the rounded corners of radii equal to 0.5 mm needed to fabricate the structure using CNC milling. The final dimensions of the device are given in Table 1, including the required tapers employed to reach to the standard WR-75 waveguide ports. Each taper $t_i$ consists of three sections with different heights, $h_i$, and lengths, $l_i$. The structure has been fabricated using bare aluminium in two halves (see Figure 7) along the E-plane. The simulated response (red line) is in excellent agreement with the measured frequency response (black line), as shown in Figure 8. The measured in-band return loss is better than 20 dB and the measured insertion loss is 0.22 dB at the centre frequency of the passband. The insertion loss detail is given in the inset of Figure 8.

**Conclusion:** A design technique to add multiple and fully controlled TZs to improve the selectivity of commensurate-line stepped-impedance BPFs has been presented. It allows us to replace one of the DEs with the proposed M-SADE, which permits us to include M TZs below or above the passband of the filter as demanded. The technique requires us to redesign one filter section only while the rest can be kept unaltered. The technique has been tested with a filter for Ku-band applications (10.7–12.75 GHz), including four TZs around the passband. The final device has been fabricated by CNC milling in aluminium, confirming the simulated frequency response. Therefore, the proposed technique can be considered an interesting alternative to design BPFs with a wide passband and TZs below and above this passband.

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**Conflict of interest:** The authors declare no conflict of interest.

**Data availability statement:** Data sharing not applicable to this article as no datasets were generated or analyzed during the current study.

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